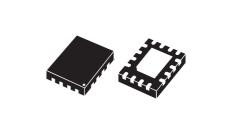


STG3692

Low voltage high bandwidth quad SPDT switch

Features

- Ultra low power dissipation:
 - I_{CC} = 0.2 µA (max.) at T_A = 85 °C
- Low "ON" resistance:
 - $R_{ON} = 4.6 \Omega (T_A = 25 °C) at V_{CC} = 4.3 V$
 - $R_{ON} = 5.8 \Omega (T_A = 25 °C) at V_{CC} = 3.0 V$
- Wide operating voltage range:
 V_{CC} (opr) = 1.65 V to 4.3 V single supply
- 4.3 V tolerant and 1.8 V compatible threshold on digital control input at V_{CC} = 2.3 V to 3.0 V
- Typical bandwidth (-3 dB) at 800 MHz on all channels
- Latch-up performance exceeds 100 mA per JESD 78, Class II
- ESD performance exceeds JESD22
 2000-V human body model (A114-A)
- USB (2.0) high-speed (480 Mbps) signal switching compliant



QFN16L (2.6mm x 1.8mm)

Description

The STG3692 is a high-speed CMOS low voltage quad analog S.P.D.T. (single pole dual throw) switch or 2:1 multiplexer/demultiplexer switch fabricated in silicon gate C^2MOS technology. It is designed to operate from 1.65 V to 4.3 V, making this device ideal for portable applications.

The nSEL inputs are provided to control the switch. The switch S1 is ON (connected to common ports Dn) when the nSEL input is held high and OFF (high impedance state exists between the two ports) when SEL is held low; the switch S2 is ON (it is connected to common port D) when the nSEL input is held low and OFF (high impedance state exists between the two ports) when nSEL is held high.

Additional key features are fast switching speed, break-before-make delay time and ultra low power consumption. All inputs and outputs are equipped with protection circuits against static discharge, giving them ESD immunity and transient excess voltage.

Table 1. Device summary

Order code	Package	Packing
STG3692QTR	QFN16L (2.6 x 1.8 mm)	Tape and reel

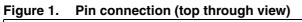
Contents

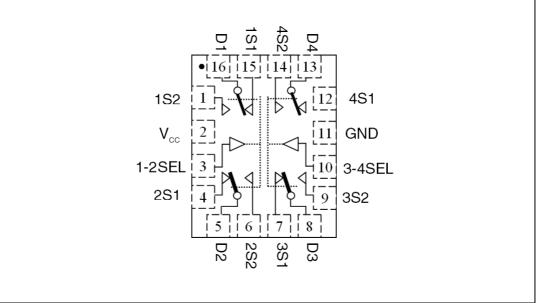
1	Pin settings 3
	1.1 Pin connection
	1.2 Pin description
2	Device summary
3	Maximum rating
	3.1 Recommended operating conditions 5
4	Electrical characteristics
5	Test circuits
6	Package mechanical data 13
7	Revision history



1 Pin settings

1.1 Pin connection





1.2 Pin description

Pin number	Symbol	Name and function
15,1, 4,6, 7,9, 12,14	1S1, 1S2, 2S1, 2S2, 3S1, 3S2, 4S1, 4S2	Independent channels
16,5,8,13	D1, D2, D3, D4	Common channels
3, 10	1-2SEL, 3-4SEL	Control
2	V _{CC}	Positive supply voltage

Note:

Exposed pad must be soldered to a floating plane. Do NOT connect to power or ground.



2 Device summary

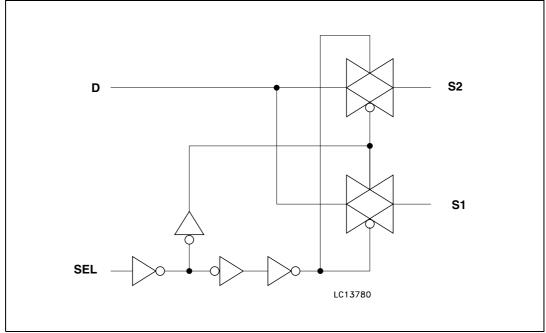


Figure 2. Input equivalent circuit

Table 3. Truth table

SEL	Switch S1	Switch S2
Н	ON	OFF ⁽¹⁾
L	OFF ⁽¹⁾	ON

1. High impedance.



3 Maximum rating

Stressing the device above the rating listed in the absolute maximum ratings table may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Symbol	Parameter	Value	Unit
V _{CC}	Supply voltage	-0.5 to 5.5	V
VI	DC input voltage	-0.5 to V _{CC} + 0.5	V
V _{IC}	DC control input voltage	-0.5 to 5.5	V
V _O	DC output voltage	-0.5 to V _{CC} + 0.5	V
I _{IKC}	DC input diode current on control pin (V _{SEL} <0 V)	-50	mA
۱ _{IK}	DC input diode current (V _{SEL} <0 V)	±50	mA
Ι _{ΟΚ}	DC output diode current	±20	mA
۱ ₀	DC output current	±128	mA
I _{OP}	DC output current peak (pulse at 1 ms, 10% duty cycle)	±300	mA
$I_{\rm CC}$ or $I_{\rm GND}$	DC V _{CC} or ground current	±100	mA
PD	Power dissipation at $T_A = 70 \degree C^{(1)}$	1120	mW
T _{stg}	Storage temperature	-65 to 150	°C
ΤL	Lead temperature (10 sec)	300	°C

Table 4. Absolute maximum ratings

1. Derate above 70 °C by 18.5 mW/C.

3.1 Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Paramete	Value	Unit		
V _{CC}	Supply voltage ⁽¹⁾		1.65 to 4.3	V	
VI	Input voltage	0 to V _{CC}	V		
V _{IC}	Control input voltage	0 to 4.3	V		
Vo	Output voltage		0 to V _{CC}	V	
T _{op}	Operating temperature		-40 to 85	°C	
dt/dy	Input rise and fall time control	V_{CC} = 1.65 V to 2.7 V	0 to 20	ns/V	
dt/dv	input	V _{CC} = 3.0 to 4.3 V	0 to 10	115/ V	

1. Truth table guaranteed: 1.2 V to 4.3 V.



4 **Electrical characteristics**

Symbol	Parameter	V _{CC} (V)	Test conditions	Test conditions $T_A = 25^{\circ}C$;	-40 to	85°C	Unit	
		(-)		Min	Тур	Мах	Min	85°C Max 	
		1.65 – 1.95		$0.65V_{CC}$	_	-	$0.65V_{CC}$	-	
	L l'ada Javaal	2.3 – 2.5		1.2	_	_	1.2	_	
V _{IH}	High level input voltage	2.7 – 3.0		1.3	_	-	1.3	-	V
	par renage	3.3 – 3.6		1.4	-	-	1.4	-	
		4.3		1.6	_	_	1.6	-	
		1.65 – 1.95		-	-	0.25	-	-	
		2.3 – 2.5		-	_	0.25	-	-	
VII	Low level input voltage	2.7 – 3.0		-	-	0.25	-	-	V
	input voitage	3.3 – 3.6		-	-	0.30	-	-	
		4.3		-	-	0.40	-	-	
		1.8	$V_{S} = 0 V \text{ to } V_{CC}$ $I_{S} = 8 \text{ mA}$	-	12.0	16.0	-	-	Ω
R _{PEAK}	Switch ON peak resistance	2.7		-	6.3	8.0	-	-	
		3.0		-	5.8	7.5	-	-	
		3.7		-	5.0	6.5	-	-	
		4.3	-	_	4.6	6.0	-	-	1
Reu	Switch On	3.0 ch On	$V_S = 3 V$ $I_S = 8 mA$	_	4.0	5.2	_	_	Ω
R _{ON}	resistance	3.0	V _S = 0.8 V I _S = 8 mA	-	5.0	6.5	-	-	52
	ON	1.8		-	-	-	-	-	
	resistance	2.7		-	-	-	-	-	
ΔR_{ON}	match	3.0	V _S at R _{ON} max I _S = 8 mA	-	0.3	-	_	-	Ω
	between channels ⁽¹⁾	3.7	- 15 - 0 11# 1	-	-	-	_	-	
	channels ()	4.3		-	-	-	_	-	
		1.8		-	6.6	_	-	-	
	ON	2.7		-	2.0	_	-	-	
R _{FLAT}	resistance	3.0	$V_S = 0$ V to V_{CC} $I_S = 8$ mA	-	1.7	_	-	-	Ω
	flatness ⁽²⁾	3.7		-	1.5	_	-	-	
		4.3	1	_	1.6	-	-	-	
I _{OFF}	OFF state leakage current (SN), (D)	4.3	V _S = 0.3 or 4 V	_	_	±20	-	±100	nA

Table 6.DC specifications



Symbol	Parameter	V _{CC} (V)	Test conditions	T _A = 25°C			-40 to	Unit	
				Min	Тур	Max	Min	Max	
I _{IN}	Input leakage current	0 to 4.3	V _{SEL} = 0 to 4.3 V	_	_	±0.1	_	±1	μA
I _{CC}	Quiescent supply current	1.65 to 4.3	$V_{SEL} = V_{CC}$ or GND	_	_	±0.1	_	±1.0	μA
	Quiescent		V _{1-2SEL,} V _{3-4SEL} = 1.65 V	_	±37	±50	_	±100	
I _{CCLV}	supply current low voltage	4.3	V _{1-2SEL,} V _{3-4SEL} = 1.80 V	_	±33	±40	_	±50	μA
	driving		V _{1-2SEL,} V _{3-4SEL} = 2.60 V	_	±11	±20	_	±30	

Table 6. DC specifications (continued)

1. Note 1: $\Delta Ron = max |mSN-nSN|$, where m = 1..4 and n = 1..4, N = 1..2

2. Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal ranges.

Symbol	Parameter	V _{CC} (V)	Test conditions		T _A = 25°0	0	-40 to	o 85°C	Unit	
				Min	Тур	Max	Min	Max		
		1.65 – 1.95		-	0.30	—	-	-		
t _{PLH} , t _{PHL}	Propagation	2.3 – 2.7		Ι	0.30	_	_	_	ns	
PLH, PHL	delay	3.0 – 3.3		Ι	0.25	_	_	_	115	
		3.6 – 4.3		Ι	0.25	_	_	_		
		1.65 – 1.95	V _S = 0.8 V	-	31	_	_	_		
t _{ON}	Turn-ON time	2.3 – 2.7	V _S = 1.5 V	-	20	26	-	34	ns	
UN		3.0 - 3.3		-	15	20	-	26		
		3.6 – 4.3		Ι	12	15	_	20		
		1.65 – 1.95	V _S = 0.8	-	22	-	_	_		
t _{OFF}	Turn-OFF	2.3 – 2.7		-	14	18	-	23	ne	
OFF	time	3.0 - 3.3	V _S = 1.5 V	1	11	14	-	18	ns	
		3.6 – 4.3		Ι	10	13	_	17		
		1.65 – 1.95	C = 25 pE	1	7	_	_	_		
t _D	Break- before-make	2.3 – 2.7	- R _L = 50 Ω	- C _L = 35 pF - R _L = 50 Ω - V _S = 1.5 V	1	5	_	_	_	ns
U ^v	time delay	3.0 – 3.3			1	4	_	_	—	- 115
		3.6 – 4.3		1	3	-	-	—		

Table 7.AC electrical characteristics (C_L = 35 pF, R_L = 50 Ω , t_r = $t_f \le 5$ ns)



				Value					
Symbol	Parameter	er V _{CC} Test conditions T _A		T _A = 25°C	2	-40 to 85°C		Unit	
				Min	Тур	Max	Min	Max	
		1.65	0 100 - 5	-	2.8	—	—	-	
Q	Charge	2.3	C _L = 100 pF V _{GEN} = 0 V	-	3.5	_	_	_	рС
Q	injection	3.0	$R_{GEN} = 0 \Omega$	_	3.8	-	-	-	ρο
		4.3	GEN	-	5.0	-	-	-	

Table 7.AC electrical characteristics (C_L = 35 pF, R_L = 50 Ω , t_r = $t_f \le 5$ ns) (continued)

Table 8.Analog switch characteristics ($C_L = 5 \text{ pF}, R_L = 50 \Omega, T_A = 25 ^{\circ}C$)

		٦	Test conditions	Value					Unit
Symbol	Parameter	Nos (II)		T _A = 25°C			-40 to 85°C		
		Vcc (V)		Min	Тур	Max	Min	Max	
0 _{IRR}	OFF isolation ⁽¹⁾	1.65 -4.3	$V_S = 1V_{RMS,} f = 1 MHz$ Signal = 0 dBm	-	-79	_	-	-	dB
OIRK	OFF Isolation ()	1.00 -4.0	$V_S = 1V_{RMS,} f = 10 MHz$ Signal = 0 dBm	_	-60	_	_	_	UD
X Q A H	1.65 - 4.3	$V_S = 1V_{RMS,} f = 1 MHz$ Signal = 0 dBm	_	-78	_	_	_	dB	
X _{talk}	Crosstalk	Staik 1.00 - 4.0	$V_S = 1V_{RMS,} f = 10 MHz$ Signal = 0 dBm	_	-61	_	_	_	UD
B _W	-3dB bandwidth	3.0 - 4.3	R _L = 50Ω Signal = 0 dBm	_	800	_	_	_	MHz
D _G	Differential gain	3.0 - 4.3	R _L = 150 Ω	-	0.64	-	-	-	%
D _P	Differential phase	3.0 - 4.3	R _L = 150 Ω	_	0.1	-	_	-	deg
C _{IN}	Control pin input capacitance		V _{CC} = 0 V	_	6.2	_	_	-	
C _{ON}	Sn port capacitance when switch is enabled	3.3	f = 1 MHz	_	12	_	_	_	pF
C _{OFF}	Sn port capacitance when switch is disabled	3.3	f = 1 MHz	_	5	_	_	_	

1. Off isolation = 20Log10 (V_D/V_S), V_D = output. V_S = input to off switch.



Symbol	Parameter	V _{CC} (V)	Test conditions	Value					
				T _A = 25°C			-40 to 85°C		Unit
				Min	Тур	Max	Min	Max	
t _{SK(0)}	Channel-to-channel skew	3.0 to 3.6	C _L =10 pF	-	26	_	-	-	ps
t _{SK(P)}	Skew of opposite transition of the same output	3.0 to 3.6	C _L =10 pF	Ι	60	_	Ι	Ι	ps
ТJ	Total jitter	3.0 to 3.6	$R_L = 50 \Omega,$ $C_L = 10 pF,$ $t_R = t_F = 750 ps$ at 480 Mbps	-	130	-	-	-	ps

Table 9. USB related AC electrical characteristics



5 Test circuits

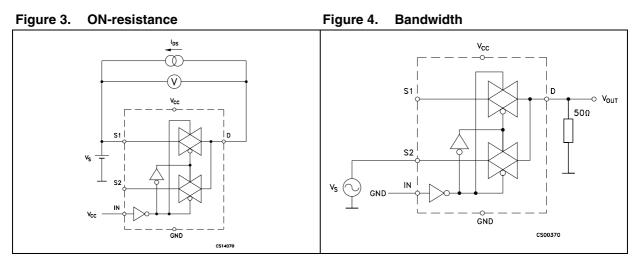
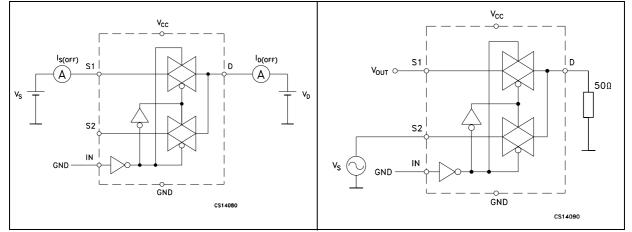




Figure 6. Channel to channel crosstalk





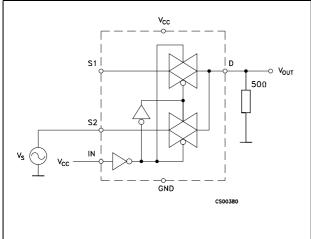
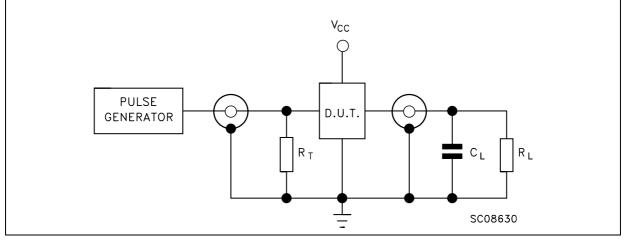


Figure 8. Test circuit



- *Note:* 1 $C_L = 5/35$ pF or equivalent: (includes jig capacitance)
 - 2 $R_L = 50 \Omega$ or equivalent
 - 3 $R_T = Z_{OUT}$ of pulse generator (typically 50 Ω)



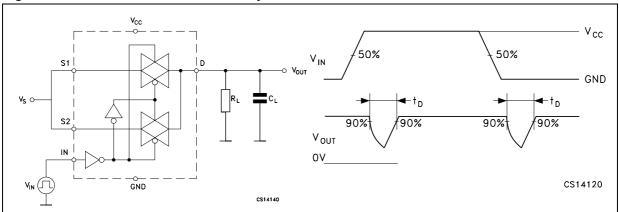
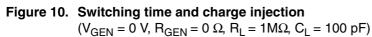


Figure 9. Break-before-make time delay



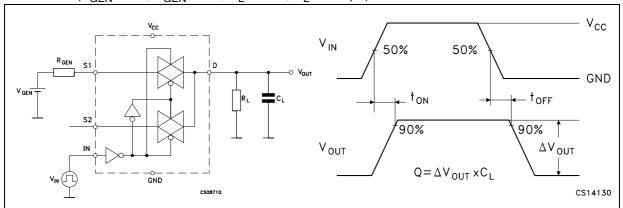
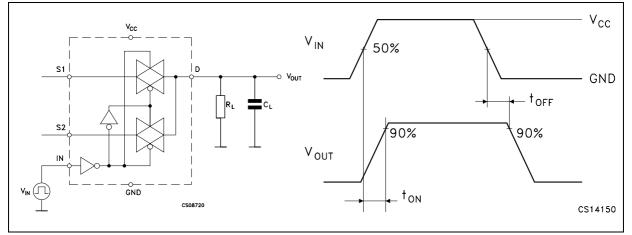


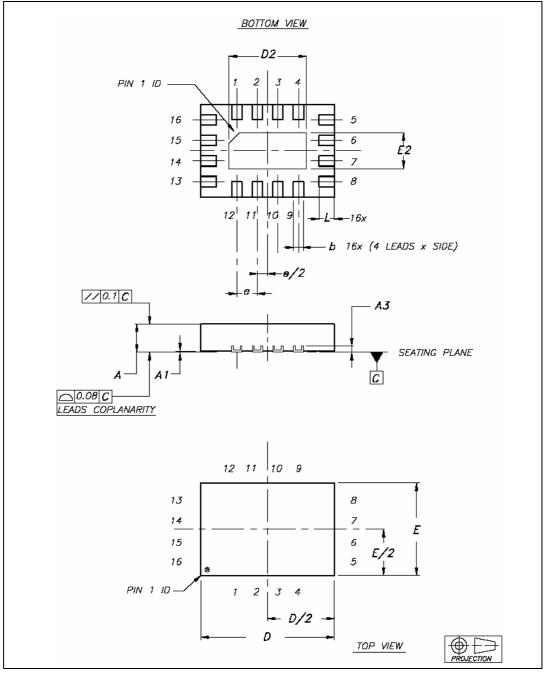
Figure 11. Turn ON, turn OFF delay time





6 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK[®] is an ST trademark.







Symbol	Millimeters					
Symbol	Min	Тур	Мах			
A	0.45	0.50	0.55			
A1	0	0.02	0.05			
A3		0.127				
b	0.15	0.20	0.25			
D	2.50	2.60	2.70			
D2	1.40	1.50	1.60			
E	1.70	1.80	1.90			
E2	0.60	0.70	0.80			
е		0.40				
L	0.25	0.30	0.35			

Table 10. QFN16L (2.6 x 1.8 mm) mechanical data

Note:

1 VFQFPN - Standard for thermally enhanced vey fine pitch quad flat package no leads.

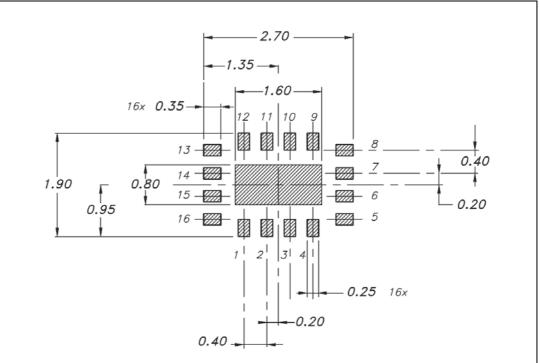
2 The leads size is comprehensive of the thickness of the leads finishing material.

3 Dimensions do not include mold protusion.

4 Package outline exclusive of metal burrs dimensions.

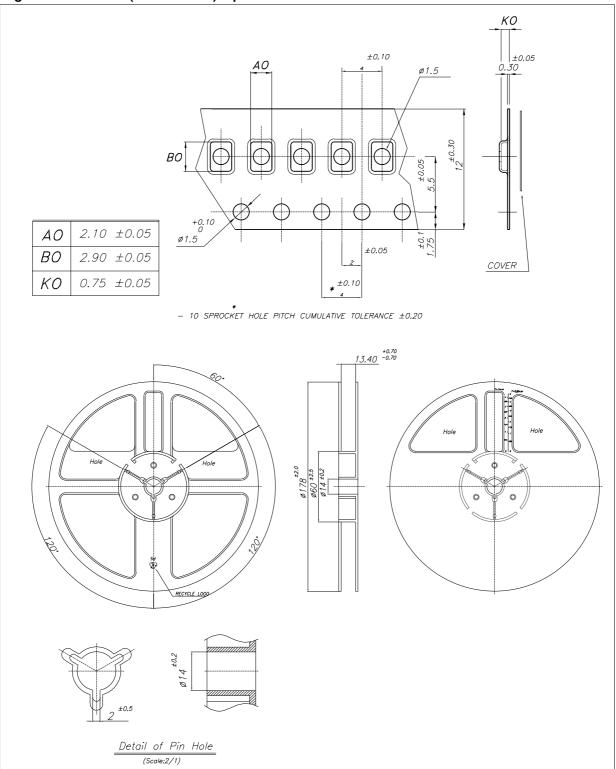
5 Shipping media tape and reel units: 3000

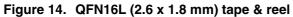
Figure 13. Footprint recommendation



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7 Revision history

Table 11. Document revision history

Date	Revision	Changes
11-Oct-2006	1	Initial release.
08-Nov-2006	2	Added feature in cover page.
08-Jan-2007	3	Mechanical data updated.
03-Jul-2007	4	C _{ON} and C _{OFF} values updated on <i>Table 8 on page 8</i> .
05-May-2010	5	Document reformatted no content change.
30-Jun-2010	6	Update of product maturity.



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